VS-SC80FA65



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SOT-227 Silicon Carbide Schottky Barrier Diode, 650 V, 80 A



PRIMARY CHARACTERISTICS						
V _R	650 V					
V _F (typical) at 40 A, per diode	1.36 V					
Q _C (typical), per diode	110 nC					
$I_{F(DC)}$ per module at $T_C = 130 \ ^{\circ}C$	80 A					
Туре	Modules - diode, SiC Schottky					
Package	SOT-227					
Circuit configuration	Two separate diodes, parallel pin-out					

FEATURES

· Virtually no recovery tail and no switching losses



- Majority carrier diode using Schottky technology on SiC wide band gap material
- RoHS COMPLIANT
- Improved V_F and efficiency by thin wafer technology
- High speed switching, low switching losses
- Positive temperature coefficient, for easy paralleling
- · Electrically isolated base plate
- Large creepage distance between terminal
- Simplified mechanical designs, rapid assembly
- · Designed and qualified for industrial level
- UL approved file E78996
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

Wide band gap SiC based 650 V Schottky diode, designed for high performance and ruggedness.

Optimum choice for high speed hard switching and efficient operation over a wide temperature range, it is also recommended for all applications suffering from Silicon ultrafast recovery behavior.

Typical applications include AC/DC PFC and DC/DC ultra high frequency output rectification in FBPS and LLC converters

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS		
Cathode to anode voltage	V _R		650	V		
Continuous forward current per diode	١ _F	T _C = 130 °C	40	٨		
Single pulse forward current per diode	I _{FSM}	$T_J = 25 \ ^{\circ}C$, 6 ms square pulse	225	A		
Maximum power dissipation per module	PD	T _C = 130 °C	150	W		
RMS isolation voltage	V _{ISOL}	Any terminal to case, t = 1 min	2500	V		
Operating junction and storage temperature range	T _J , T _{Stg}		-55 to +175	°C		

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V _{BR}	I _R = 200 μA	650	-	-	
Forward voltage	V _{FM}	I _F = 40 A	-	1.36	1.58	V
		I _F = 40 A, T _J = 150 °C	-	1.58	-	
		V _R = 650 V	-	1.8	80	
Reverse leakage current	I _{RM}	T _J = 125 °C, V _R = 650 V	-	6.0	-	μA
		$T_{J} = 150 \ ^{\circ}C, V_{R} = 650 \ V$	-	8.7	-	
Junction capacitance	CT	V _R = 650 V, f = 1 MHz	-	161	-	pF

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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 $^{\circ}$ C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Total capacitive charge	Q _C	V _R = 400 V	-	110	-	nC

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal resistance junction to case, per diode	P		-	-	0.60	
Thermal resistance junction to case, per module	R _{thJC}		-	-	0.30	°C/W
Thermal resistance case to heatsink, per module	R _{thCS}	Flat, greased surface	-	0.05	-	
Weight			-	30	-	g
Mounting torque		Torque per diode	-	-	1.1 (9.7)	Nm (lbf.in)
		Torque to heatsink	-	-	1.8 (15.9)	Nm (lbf.in)
Case style				SOT	-227	

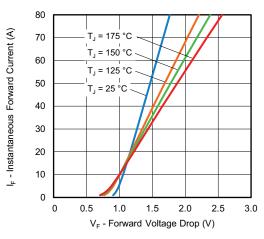


Fig. 1 - Typical Forward Voltage Drop Characteristics

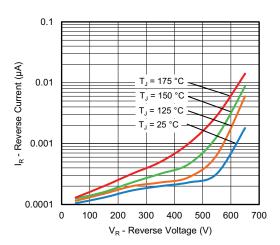


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

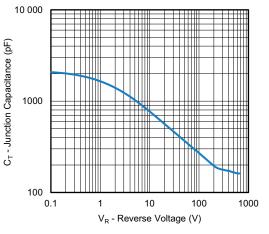


Fig. 3 - Junction Capacitance vs. Reverse Voltage

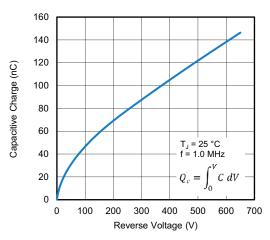


Fig. 4 - Typical Capacitive Charge vs. Reverse Voltage

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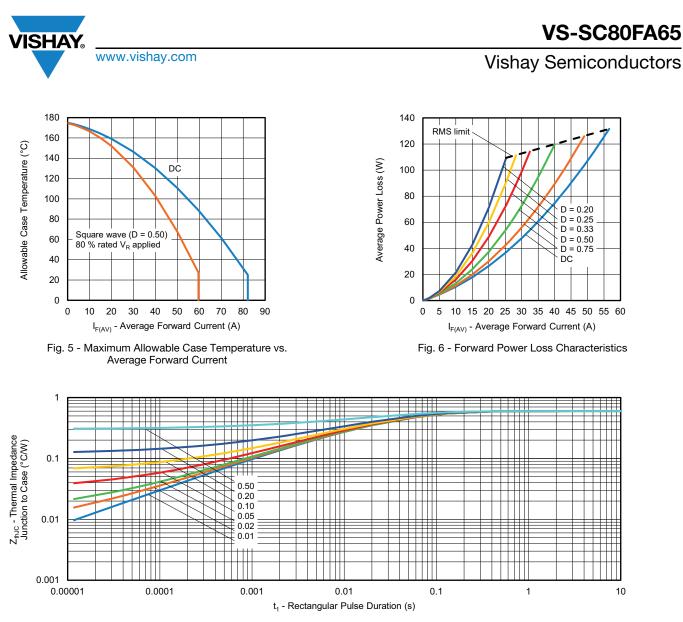


Fig. 7 - Maximum Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

Device code VS-SC 80 F Α 65 (3) 1 2 4 5 6 Vishay Semiconductors product 2 SC = SiC Schottky Barrier Diode Current rating per module (80 = 80 A) 3 _ 4 F = circuit configuration (two separate diodes, parallel pin-out) 5 Package indicator (SOT-227 standard insulated base) _ 6 Voltage rating (65 = 650 V)



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CIRCUIT CONFI	CIRCUIT CONFIGURATION					
CIRCUIT	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING				
Two separate diodes, parallel pin-out	F	Lead Assignment				

LINKS TO RELATED DOCUMENTS				
Dimensions www.vishay.com/doc?95423				
Packaging information	www.vishay.com/doc?95425			

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SOT-227 Generation 2

DIMENSIONS in millimeters (inches)



Note

• Controlling dimension: millimeter



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